

SBS 1.1-COMPLIANT GAS GAUGE and PROTECTION ENABLED WITH IMPEDANCE TRACK™

Check for Samples: bq20z95

FEATURES

- Next Generation Patented Impedance Track[™] **Technology Accurately Measures Available** Charge in Li-Ion and Li-Polymer Batteries
 - Better Than 1% Error Over Lifetime of the **Batterv**
- Supports the Smart Battery Specification • **SBS V1.1**
- Flexible Configuration for 2-Series to 4-Series Li-lon and Li-Polymer Cells
- Powerful 8-Bit RISC CPU With Ultra-Low **Power Modes**
- **Full Array of Programmable Protection Features**
 - Voltage, Current, and Temperature
- **Supports SHA-1 Authentication**
- **Complete Battery Protection and Gas Gauge** Solution in One Package
- Small 44-Pin TSSOP (DBT) Package

APPLICATIONS

- **Notebook PCs**
- Medical and Test Equipment
- **Portable Instrumentation**

DESCRIPTION

The bg20z95 SBS-compliant gas gauge and protection IC is a single IC solution designed for battery-pack or in-system installation. The bg20z95 measures and maintains an accurate record of available charge in Li-Ion or Li-Polymer batteries its integrated high-performance using analog peripherals, monitors capacity change, battery impedance, open-circuit voltage, and other critical parameters of the battery pack as well and reports the information to the system host controller over a Together serial-communication bus. with the integrated analog front-end (AFE) short-circuit and overload protection, the bq20z95 maximizes functionality and safety while minimizing external component count, cost, and size in smart battery circuits.

The implemented Impedance Track[™] gas gauging technology continuously analyzes the battery resulting in superior impedance. gas-gauging accuracy. This enables remaining capacity to be calculated with discharge rate, temperature, and cell aging all accounted for during each stage of every cycle with high accuracy.

Table 1. AVAILABLE OPTIONS

-	PACKAGE ⁽¹⁾		
I A	44-PIN TSSOP (DBT) Tube	44-PIN TSSOP (DBT) Tape and Reel	
-40°C to 85°C	bq20z95DBT ⁽²⁾	bq20z95DBTR ⁽³⁾	

(1) For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI website at www.ti.com.

A single tube quantity is 50 units. (2)

(3)A single reel quantity is 2000 units.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet. Impedance Track is a trademark of Texas Instruments.

bq20z95



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This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

SYSTEM PARTITIONING DIAGRAM



bq20z95 DBT Package (TOP VIEW)

			1
DSG 🗆	1•	44	CHG
PACK	2	43	BAT
VCC 🗆	3	42	VC1
ZVCHG	4	41	VC2
GPOD	5	40	VC3
PMS	6	39	VC4
VSS 🗆	7	38	VC5
REG33	8	37	ASRP
TOUT	9	36	ASRN
VCELL+	10	35	RESET
ALERT	11	34	VSS
NC 🗆	12	33	🗆 RBI
TS1 🗆	13	32	REG25
TS2 🗆	14	31	
PRES 🗌	15	30	MRST
PFIN 🗆	16	29	☐ GSRN
SAFE 🗆	17	28	☐ GSRP
SMBD	18	27	LED5
NC 🗆	19	26	LED4
SMBC 🗆	20	25	LED3
DISP 🗆	21	24	LED2
VSS 🗆	22	23	LED1
			1



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TERMINAL FUNCTIONS

TE	RMINAL	I/O ⁽¹⁾	DESCRIPTION
NO.	NAME	10.7	
1	DSG	0	High-side N-chan discharge FET gate drive
2	PACK	IA, P	Battery pack input voltage sense input. It also serves as device wake up when device is in SHUTDOWN mode.
3	VCC	Ρ	Positive device supply input. Connect to the center connection of the CHG FET and DSG FET to ensure device supply either from battery stack or battery pack input.
4	ZVCHG	0	P-chan pre-charge FET gate drive
5	GPOD	OD	High voltage general purpose open drain output. Can be configured to be used in pre-charge condition.
6	PMS	I	PRE-CHARGE mode setting input. Connect to PACK to enable 0-V pre-charge using charge FET connected at CHG pin. Connect to VSS to disable 0-V pre-charge using charge FET connected at CHG pin.
7	VSS	Р	Negative device power supply input. Connect all VSS pins together for operation of device.
8	REG33	Р	3.3-V regulator output. Connect at least a 2.2-µF capacitor to REG33 and VSS.
9	TOUT	Р	Thermistor bias supply output
10	VCELL+	_	Internal cell voltage multiplexer and amplifier output. Connect a $0.1\mbox{-}\mu\mbox{F}$ capacitor to VCELL+ and VSS.
11	ALERT	I/OD	Alert output. In case of short circuit condition, overload condition and watchdog time out this pin wil be triggered.
12	NC	—	Not connected
13	TS1	IA	Temperature sensor 1 input
14	TS2	IA	Temperature sensor 2 input
15	PRES	I/OD	System/Host present input
16	PFIN	I/OD	Fuse blow detection input
17	SAFE	I/OD	Blow fuse signal output
18	SMBD	I/OD	SMBus data line
19	NC	_	Not connected
20	SMBC	I/OD	SMBus clock line
21	DISP	I/OD	Display enable input
22	VSS	Р	Negative device power supply input. Connect all VSS pins together for operation of device.
23	LED1	I	LED 1 current sink input
24	LED2	I	LED 2 current sink input
25	LED3	I	LED 3 current sink input
26	LED4	I	LED 4 current sink input
27	LED5	I	LED 5 current sink input
28	GSRP	IA	Coulomb counter differential input. Connect to one side of the sense resistor.
29	GSRN	IA	Coulomb counter differential input. Connect to one side of the sense resistor.
30	MRST	I	Reset input for internal CPU core. Connect to RESET for correct operation of device.
31	VSS	Р	Negative device power supply input. Connect all VSS pins together for operation of device.
32	REG25	P	2.5-V regulator output. Connect at least a $1-\mu$ F capacitor to REG25 and VSS.
33	RBI	Р	RAM backup input. Connect a capacitor to this pin and VSS to protect loss of RAM data in case of short circuit condition.
34	VSS	Р	Negative device power supply input. Connect all VSS pins together for operation of device.
35	RESET	0	Reset output. Connect to MSRT.
36	ASRN	IA	Short circuit and overload detection differential input. Connect to sense resistor.
37	ASRP	IA	Short circuit and overload detection differential input. Connect to sense resistor.
38	VC5	IA, P	Cell voltage sense input and cell balancing input for the negative voltage of the bottom cell in cell stack.
39	VC4	IA, P	Cell voltage sense input and cell balancing input for the positive voltage of the bottom cell and the negative voltage of the second lowest cell in cell stack.

(1) I = Input, IA = Analog input, I/O = Input/output, I/OD = Input/Open-drain output, O = Output, OA = Analog output, P = Power

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STRUMENTS

EXAS

TERMINAL FUNCTIONS (continued)

TE	RMINAL	I/O ⁽¹⁾	DESCRIPTION
NO.	NAME	1/0 (/	DESCRIPTION
40	VC3	IA, P	Cell voltage sense input and cell balancing input for the positive voltage of the second lowest cell in cell stack and the negative voltage of the second highest cell in 4-series cell applications.
41	VC2	IA, P	Cell voltage sense input and cell balancing input for the positive voltage of the second highest cell and the negative voltage of the highest cell in 4 cell applications. Connect to VC3 in 2-cell stack applications.
42	VC1	IA, P	Cell voltage sense input and cell balancing input for the positive voltage of the highest cell in cell stack in 4-cell applications. Connect to VC2 in 3- or 2-series cell applications.
43	BAT	I, P	Battery stack voltage sense input
44	CHG	0	High side N-chan charge FET gate drive

ABSOLUTE MAXIMUM RATINGS

Over Operating Free-Air Temperature (unless otherwise noted) ⁽¹⁾

	DESCRIPTION	PIN	UNIT
		VBAT, VCC	–0.3 V to 34 V
		PACK, PMS	–0.3 V to 34 V
V _{SS}	Supply voltage range	VC(n)-VC(n+1); n = 1, 2, 3, 4	–0.3 V to 8.5 V
		VC1, VC2, VC3, VC4	–0.3 V to 34 V
		VC5	–0.3 V to 1 V
		PFIN, SMBD, SMBC, LED1, LED2, LED3, LED4, LED5, DISP	-0.3 V to 6 V
V _{IN}	Input voltage range	TS1, TS2, SAFE, VCELL+, PRES; ALERT	–0.3 V to V $_{\rm (REG25)}$ + 0.3 V
		MRST, GSRN, GSRP, RBI	-0.3 V to V _(REG25) + 0.3 V
		ASRN, ASRP	-1 V to 1 V
		DSG, CHG, GPOD	–0.3 V to 34 V
		ZVCHG	–0.3 V to V _(BAT)
V _{OUT}	Output voltage range	TOUT, ALERT, REG33	–0.3 V to 6 V
		RESET	–0.3 V to 7 V
		REG25	–0.3 V to 2.75 V
I _{SS}	Maximum combined sink current for input pins	PRES, PFIN, SMBD, SMBC, LED5, LED4, LED3, LED2, LED1	50 mA
T _A	Operating free-air temperature range		-40°C to 85°C
T _F	Functional temperature		-40°C to 100°C
T _{stg}	Storage temperature range		–65°C to 150°C

(1) Stresses beyond those listed under absolute maximum ratings may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under recommended operating conditions is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

RECOMMENDED OPERATING CONDITIONS

over operating free-air temperature range (unless otherwise noted)

	PARAMETER	PIN	MIN	NOM	MAX	UNIT
V _{SS}	Supply voltage	VCC, VBAT	4.5		25	V
V _(STARTUP)	Minimum startup voltage	VCC, BAT, PACK	5.5			V
		VC(n) – VC(n+1); n = 1,2,3,4	0		5	V
		VC1, VC2, VC3, VC4	0		V _{SUP}	V
V _{IN}	Input Voltage Range	VC5	0		0.5	V
		ASRN, ASRP	-0.5		0.5	V
		PACK, PMS	0		25	V
V _(GPOD)	Output Voltage Range	GPOD	0		25	V
A _(GPOD)	Drain Current ⁽¹⁾	GPOD			1	mA
C _(REG25)	2.5-V LDO Capacitor	REG25	1			μF
C _(REG33)	3.3-V LDO Capacitor	REG33	2.2			μF
C _(VCELL+)	Cell Voltage Output Capacitor	VCELL+	0.1			μF
C _(PACK)	PACK input block resistor ⁽²⁾	РАСК	1			kΩ

(1) Use an external resistor to limit the current to GPOD to 1mA in high voltage application.

(2) Use an external resistor to limit the inrush current PACK pin required.

ELECTRICAL CHARACTERISTICS

over operating free-air temperature range (unless otherwise noted), $T_A = -40^{\circ}C$ to 85°C, $V_{(REG25)} = 2.41$ V to 2.59 V, $V_{(BAT)} = 14$ V, $C_{(REG25)} = 1$ µF, $C_{(REG33)} = 2.2$ µF; typical values at $T_A = 25^{\circ}C$ (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
SUPPLY CUR	RENT	·	· ·			
I(NORMAL)	Firmware running			550		μA
	SLEEP Mode	CHG FET on; DSG FET on		124		μA
I(SLEEP)		CHG FET off; DSG FET on		90		μA
		CHG FET off; DSG FET off		52		μA
I(SHUTDOWN)	SHUTDOWN Mode			0.1	1	μA
SHUTDOWN V	NAKE; T _A = 25°C (unless otherwise no	ted)				
I(PACK)	Shutdown exit at VSTARTUP threshold				1	μA
SRx WAKE FR	ROM SLEEP; T _A = 25°C (unless otherw	ise noted)				+
V _(WAKE)	Positive or negative wake threshold with 1.00 mV, 2.25 mV, 4.5 mV and 9 mV programmable options		1.25		10	mV
		$V_{(WAKE)} = 1 \text{ mV};$ $I_{(WAKE)} = 0, \text{ RSNS1} = 0, \text{ RSNS0} = 1$	-0.7		0.7	
V			-0.8		0.8	- mV
V _(WAKE_ACR)	Accuracy of V _(WAKE)		-1.0		1.0	mv
		$V_{(WAKE)} = 9 \text{ mV};$ $I_{(WAKE)} = 1, \text{ RSNS1} = 1, \text{ RSNS0} = 1$	-1.4		1.4	
V _(WAKE_TCO)	Temperature drift of V _(WAKE) accuracy			0.5		%/°C
t _(WAKE)	Time from application of current and wake of bq20z95			1	10	ms
POWER-ON R	ESET					
V _{IT-}	Negative-going voltage input	Voltage at REG25 pin	1.70	1.80	1.90	V
V _{hys}	Hysteresis	$V_{IT+} - V_{IT-}$	50	150	250	mV
t _{RST}	RESET active low time	Active low time after power up or watchdog reset	100	250	560	μs
WATCHDOG	TIMER					
t _{WDTINT}	Watchdog start up detect time		250	500	1000	ms

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ELECTRICAL CHARACTERISTICS (continued)

over operating free-air temperature range (unless otherwise noted), $T_A = -40^{\circ}C$ to 85°C, $V_{(REG25)} = 2.41$ V to 2.59 V, $V_{(BAT)} = 14$ V, $C_{(REG25)} = 1$ µF, $C_{(REG33)} = 2.2$ µF; typical values at $T_A = 25^{\circ}C$ (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
t _{WDWT}	Watchdog detect time		50	100	150	μs
2.5V LDO; I _{(REG}	_{333OUT)} = 0 mA; T _A = 25°C (unless oth	erwise noted)				
V _(REG25)	Regulator output voltage	4.5 < VCC or BAT < 25 V; $I_{(REG250UT)} \le 16 \text{ mA};$ $T_A = -40^{\circ}\text{C} \text{ to } 100^{\circ}\text{C}$	2.41	2.5	2.59	V
$\Delta V_{(REG25TEMP)}$	Regulator output change with temperature	$ \begin{array}{l} I_{(REG25OUT)} = 2 \text{ mA}; \\ T_A = -40^\circ\text{C} \text{ to } 100^\circ\text{C} \end{array} \end{array} $		±0.2		%
$\Delta V_{(REG25LINE)}$	Line regulation	5.4 < VCC or BAT < 25 V; I _(REG250UT) = 2 mA		3	10	mV
$\Delta V_{(REG25LOAD)}$	Load Regulation	$0.2 \text{ mA} \le I_{(\text{REG25OUT})} \le 2 \text{ mA}$ $0.2 \text{ mA} \le I_{(\text{REG25OUT})} \le 16 \text{ mA}$		7 25	25 50	mV
I _(REG25MAX)	Current Limit	Drawing current until REG25 = 2 V to 0 V	5	40	75	mA
3.3V LDO; I(REG	_{3250UT)} = 0 mA; T _A = 25°C (unless oth	erwise noted)				
V _(REG33)	Regulator output voltage	4.5 < VCC or BAT < 25 V; $I_{(REG330UT)} \le 25 \text{ mA};$ $T_A = -40^{\circ}\text{C} \text{ to } 100^{\circ}\text{C}$	3	3.3	3.6	V
$\Delta V_{(REG33TEMP)}$	Regulator output change with temperature	$I_{(REG33OUT)} = 2 \text{ mA};$ $T_A = -40^{\circ}\text{C} \text{ to } 100^{\circ}\text{C}$		±0.2		%
$\Delta V_{(REG33LINE)}$	Line regulation	5.4 < VCC or BAT < 25 V; I _(REG33OUT) = 2 mA		3	10	mV
$\Delta V_{(REG33LOAD)}$	Load Regulation	$0.2 \text{ mA} \le I_{(\text{REG33OUT})} \le 2 \text{ mA}$		7	17	mV
₩ (REG33LOAD)		$0.2\text{mA} \le I_{(\text{REG33OUT})} \le 25 \text{ mA}$		40	100	iii v
I(REG33MAX)	Current Limit	Drawing current until REG33 = 3 V	25	100	145	mA
(REG33MAX)		Short REG33 to VSS, REG33 = 0 V	12		65	
THERMISTOR	DRIVE		1		1	
V _(TOUT)	Output voltage	$I_{(TOUT)} = 0 \text{ mA}; T_A = 25^{\circ}\text{C}$		V _(REG25)		V
R _{DS(on)}	TOUT pass element resistance	$I_{(TOUT)}$ = 1 mA; $R_{DS(on)}$ = (V_{(REG25)} - V_{(TOUT)})/1 mA; T_{A} = -40°C to 100°C		50	100	Ω
VCELL+ HIGH	VOLTAGE TRANSLATION	1				
V _(VCELL+OUT)		VC(n) - VC(n+1) = 0 V; $T_A = -40^{\circ}C \text{ to } 100^{\circ}C$	0.950	0.975	1	
(VCELL+OUT)	_	VC(n) - VC(n+1) = 4.5 V; T _A = -40°C to 100°C	0.275	0.3	0.375	
$V_{(VCELL+REF)}$	Translation output	internal AFE reference voltage; $T_A = -40$ °C to 100°C	0.965	0.975	0.985	V
V _(VCELL+PACK)		Voltage at PACK pin; $T_A = -40^{\circ}$ C to 100°C	0.98 × V _(PACK) /1 8	V _(PACK) /1 8	1.02 × V _(PACK) /1 8	
V _(VCELL+BAT)		Voltage at BAT pin; $T_A = -40^{\circ}$ C to 100°C	0.98 × V _(BAT) /18	V _(BAT) /18	1.02 × V _(BAT) /18	
CMMR	Common mode rejection ratio	VCELL+	40			dB
		K= {VCELL+ output (VC5=0 V; VC4=4.5 V) - VCELL+ output (VC5=0 V; VC4=0 V)}/4.5	0.147	0.150	0.153	
К	Cell scale factor	K= {VCELL+ output (VC2=13.5V; VC1=18 V) – VCELL+ output (VC5=13.5 V; VC1=13.5 V)}/4.5	0.147	0.150	0.153	
I(VCELL+OUT)	Drive Current to VCELL+ capacitor	$\label{eq:VC} \begin{array}{l} VC(n)-VC(n+1)=0V; \ VCELL+=0 \ V; \\ T_A=-40^\circ C \ to \ 100^\circ C \end{array}$	12	18		μA
V _(VCELL+O)	CELL offset error	CELL output (VC2 = VC1 = 18 V) - CELL output (VC2 = VC1 = 0 V)	-18	-1	18	mV
I _{VCnL}	VC(n) pin leakage current	VC1, VC2, VC3, VC4, VC5 = 3 V	-1	0.01	1	μA
CELL BALANC	ING Internal cell balancing FET	R _{DS(on)} for internal FET switch at	200	400		Ω



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ELECTRICAL CHARACTERISTICS (continued)

over operating free-air temperature range (unless otherwise noted), $T_A = -40^{\circ}C$ to $85^{\circ}C$, $V_{(REG25)} = 2.41$ V to 2.59 V, $V_{(BAT)} = 14$ V, $C_{(REG25)} = 1$ µF, $C_{(REG33)} = 2.2$ µF; typical values at $T_A = 25^{\circ}C$ (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
IARDWARE S	HORT CIRCUIT AND OVERLOAD PR	ROTECTION; $T_A = 25^{\circ}C$ (unless otherwise noted)				
		V _{OL} = 25 mV (min)	15	25	35	
V _(OL)	OL detection threshold voltage accuracy	V _{OL} = 100 mV; RSNS = 0, 1	90	100	110	mV
	accuracy	V _{OL} = 205 mV (max)	185	205	225	
		V _(SCC) = 50 mV (min)	30	50	70	
V _(SCC)	SCC detection threshold voltage	V _(SCC) = 200 mV; RSNS = 0, 1	180	200	220	mV
()	accuracy	V _(SCC) = 475 mV (max)	428	475	523	
		$V_{(SCD)} = -50 \text{ mV} (\text{min})$	-30	-50	-70	
V _(SCD)	SCD detection threshold voltage	V _(SCD) = -200 mV; RSNS = 0, 1	-180	-200	-220	mV
(000)	accuracy	$V_{(SCD)} = -475 \text{ mV} \text{ (max)}$	-428	-475	-523	_
t _{da}	Delay time accuracy			±15.25		μs
t _{pd}	Protection circuit propagation delay			50		μs
	RCUIT; $T_A = 25^{\circ}C$ (unless otherwise)	noted)		00		μο
	$1_{\rm A} = 25$ C (unless otherwise)					
V _(DSGON)	DSG pin output on voltage	$V_{(DSGON)}=V_{(DSG)}-V_{(PACK)};$ $V_{(GS)}$ = 10 MΩ; DSG and CHG on; $T_A=-40^\circ C \ to \ 100^\circ C$	8	12	16	V
V _(CHGON)	CHG pin output on voltage	$V_{(CHGON)}=V_{(CHG)}-V_{(BAT)};~V_{(GS)}$ = 10 MΩ; DSG and CHG on; $T_A=-40^\circ C$ to 100°C	8	12	16	v
V _(DSGOFF)	DSG pin output off voltage	$V_{(DSGOFF)} = V_{(DSG)} - V_{(PACK)}$			0.2	V
V _(CHGOFF)	CHG pin output off voltage	$V_{(CHGOFF)} = V_{(CHG)} - V_{(BAT)}$			0.2	V
	Rise time	$C_L = 4700 \text{ pF}; V_{(PACK)} \le DSG \le V_{(PACK)} + 4V$		400	1000	
t _r		C_{L} = 4700 pF; $V_{(BAT)} \le CHG \le V_{(BAT)} + 4V$		400	1000	μs
		$C_L = 4700 \text{pF}; V_{(PACK)} + V_{(DSGON)} \le \text{DSG} \le V_{(PACK)} + 1V$		40	200	
t _f	Fall time	C_L = 4700 pF; $V_{(BAT)}$ + $V_{(CHGON)}$ ≤ CHG ≤ $V_{(BAT)}$ + 1 V		40	200	μs
V _(ZVCHG)	ZVCHG clamp voltage	BAT = 4.5 V	3.3	3.5	3.7	V
	40°C to 100°C (unless otherwise not		0.0	0.0	0.1	
				100	000	
, . <u>.</u>			60			
R _(PULLUP)	Internal pullup resistance	ALERT	60 1		200	kΩ
_	Internal pullup resistance	RESET	60 1	3	6	kΩ
R _(PULLUP)		RESET ALERT			6 0.2	
_	Internal pullup resistance	RESET ALERT RESET; V _(BAT) = 7V; V _(REG25) = 1.5 V; Ι (RESET) = 200 μA			6 0.2 0.4	kΩ V
R _(PULLUP) V _{OL}	Logic low output voltage level	RESET ALERT			6 0.2	
R _(PULLUP) V _{OL} OGIC SMBC,	Logic low output voltage level SMBD, PFIN, PRES, SAFE, ALERT	RESET ALERT RESET; V _(BAT) = 7V; V _(REG25) = 1.5 V; Ι (RESET) = 200 μA	1		6 0.2 0.4	V
R _(PULLUP) V _{OL} OGIC SMBC, V _{IH}	Logic low output voltage level SMBD, PFIN, PRES, SAFE, ALERT High-level input voltage	RESET ALERT RESET; V _(BAT) = 7V; V _(REG25) = 1.5 V; Ι (RESET) = 200 μA			6 0.2 0.4 0.6	v
R _(PULLUP) V _{OL} OGIC SMBC,	Logic low output voltage level SMBD, PFIN, PRES, SAFE, ALERT	RESET ALERT RESET; V _(BAT) = 7V; V _(REG25) = 1.5 V; Ι (RESET) = 200 μA	2.0		6 0.2 0.4	V
R _(PULLUP) V _{OL} OGIC SMBC, V _{IH}	Logic low output voltage level SMBD, PFIN, PRES, SAFE, ALERT High-level input voltage	RESET ALERT RESET; V _(BAT) = 7V; V _(REG25) = 1.5 V; Ι (RESET) = 200 μA	1		6 0.2 0.4 0.6	v v
R _(PULLUP) V _{OL} OGIC SMBC, V _{IH} V _{IL}	Logic low output voltage level SMBD, PFIN, PRES, SAFE, ALERT High-level input voltage Low-level input voltage	RESET ALERT RESET; V _(BAT) = 7V; V _(REG25) = 1.5 V; I (RESET) = 200 μA GPOD; I _(GPOD) = 50 μA	1 2.0 V _{REG25} -0		6 0.2 0.4 0.6	v
R _(PULLUP) V _{OL} OGIC SMBC, V _{IH} V _{IL} V _{OH}	Logic low output voltage level SMBD, PFIN, PRES, SAFE, ALERT High-level input voltage Low-level input voltage Output voltage high ⁽¹⁾	$\hline \hline $	1 2.0 V _{REG25} -0		6 0.2 0.4 0.6	V V V V V
R _(PULLUP) V _{OL} OGIC SMBC, V _{IH} V _{IL} V _{OH} V _{OL}	Logic low output voltage level SMBD, PFIN, PRES, SAFE, ALERT High-level input voltage Low-level input voltage Output voltage high ⁽¹⁾ Low-level output voltage	$\hline \hline $	1 2.0 V _{REG25} -0	3	6 0.2 0.4 0.6	V V V V V
R(PULLUP) V _{OL} OGIC SMBC, V _{IH} V _{IL} V _{OH} V _{OL} C ₁ I _(SAFE)	Logic low output voltage level SMBD, PFIN, PRES, SAFE, ALERT High-level input voltage Low-level input voltage Output voltage high ⁽¹⁾ Low-level output voltage Input capacitance	$\begin{tabular}{ c c c c c c c c c c c c c c c c c c c$	1 2.0 V _{REG25} -0 .5	3	6 0.2 0.4 0.6	V V V V PF
R _(PULLUP) V _{OL} OGIC SMBC, V _{IH} V _{IH} V _{IL} V _{OH} V _{OL} C _I	Logic low output voltage level SMBD, PFIN, PRES, SAFE, ALERT High-level input voltage Low-level input voltage Output voltage high ⁽¹⁾ Low-level output voltage Input capacitance SAFE source currents	$\begin{tabular}{ c c c c c c c c c c c c c c c c c c c$	1 2.0 V _{REG25} -0 .5	3	6 0.2 0.4 0.6 0.8 0.8	v v v
$\begin{array}{c} R_{(PULLUP)} \\ \hline V_{OL} \\ \hline \\$	Logic low output voltage level SMBD, PFIN, PRES, SAFE, ALERT High-level input voltage Low-level input voltage Output voltage high ⁽¹⁾ Low-level output voltage Input capacitance SAFE source currents SAFE leakage current	$\begin{tabular}{ c c c c c c c c c c c c c c c c c c c$	1 2.0 V _{REG25} -0 .5	3	6 0.2 0.4 0.6 0.8 0.8 0.4	V V V V PF mA
$\begin{array}{c} R_{(PULLUP)} \\ \hline V_{OL} \\ \hline \\$	Logic low output voltage level SMBD, PFIN, PRES, SAFE, ALERT High-level input voltage Low-level input voltage Output voltage high ⁽¹⁾ Low-level output voltage Input capacitance SAFE source currents SAFE leakage current Input leakage current	RESET ALERT RESET; $V_{(BAT)} = 7V$; $V_{(REG25)} = 1.5 V$; $I_{(RESET)} = 200 \mu A$ GPOD; $I_{(GPOD)} = 50 \mu A$ IL = -0.5 mA PRES, PFIN, ALERT, IL = 7 mA; SAFE active, SAFE = $V_{(REG25)}$ -0.6 V SAFE inactive	1 2.0 V _{REG25} -0 .5 -3 -0.2	3	6 0.2 0.4 0.6 0.8 0.8 0.4 0.2 1	V V V V V PF mA
$\begin{array}{c} R_{(PULLUP)} \\ \hline V_{OL} \\ \hline \\$	Logic low output voltage level SMBD, PFIN, PRES, SAFE, ALERT High-level input voltage Low-level input voltage Output voltage high ⁽¹⁾ Low-level output voltage Input capacitance SAFE source currents SAFE leakage current Input leakage current Input voltage range	$\begin{tabular}{ c c c c c c c c c c c c c c c c c c c$	1 2.0 V _{REG25} -0 .5	3	6 0.2 0.4 0.6 0.8 0.8 0.4	ν ν ν ν ν ν ν ν ν ν ν ν ν ν ν ν ν ν ν
$\begin{array}{c} R_{(PULLUP)} \\ \hline V_{OL} \\ \hline \\ $	Logic low output voltage level SMBD, PFIN, PRES, SAFE, ALERT High-level input voltage Low-level input voltage Output voltage high ⁽¹⁾ Low-level output voltage Input capacitance SAFE source currents SAFE leakage current Input leakage current Input voltage range Conversion time	RESET ALERT RESET; $V_{(BAT)} = 7V$; $V_{(REG25)} = 1.5 V$; $I_{(RESET)} = 200 \mu A$ GPOD; $I_{(GPOD)} = 50 \mu A$ IL = -0.5 mA PRES, PFIN, ALERT, IL = 7 mA; SAFE active, SAFE = $V_{(REG25)}$ -0.6 V SAFE inactive	1 2.0 V _{REG25} -0 .5 -3 -0.2	3	6 0.2 0.4 0.6 0.8 0.8 0.4 0.2 1	- V - V - V - V - V - V - V - μΑ - μΑ - μΑ - μΑ - μΑ - μΑ - μΑ - μΑ
R _(PULLUP) V _{OL} OGIC SMBC, V _{IH} V _{IL} V _{OH} V _{OL} C _I I _(SAFE) I _{Ikg(SAFE)}	Logic low output voltage level SMBD, PFIN, PRES, SAFE, ALERT High-level input voltage Low-level input voltage Output voltage high ⁽¹⁾ Low-level output voltage Input capacitance SAFE source currents SAFE leakage current Input leakage current Input voltage range	RESET ALERT RESET; $V_{(BAT)} = 7V$; $V_{(REG25)} = 1.5 V$; $I_{(RESET)} = 200 \mu A$ GPOD; $I_{(GPOD)} = 50 \mu A$ IL = -0.5 mA PRES, PFIN, ALERT, IL = 7 mA; SAFE active, SAFE = $V_{(REG25)}$ -0.6 V SAFE inactive	1 2.0 V _{REG25} -0 .5 -3 -0.2	3	6 0.2 0.4 0.6 0.8 0.8 0.4 0.2 1	ν ν ν ν ν ν ν ν ν ν ν

(1) RC[0:7] bus

(2) Unless otherwise specified, the specification limits are valid at all measurement speed modes.

(3) Full-scale reference



ELECTRICAL CHARACTERISTICS (continued)

over operating free-air temperature range (unless otherwise noted), $T_A = -40^{\circ}C$ to 85°C, $V_{(REG25)} = 2.41$ V to 2.59 V, $V_{(BAT)} = 14$ V, $C_{(REG25)} = 1 \,\mu$ F, $C_{(REG33)} = 2.2 \,\mu$ F; typical values at $T_A = 25^{\circ}C$ (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
	Offset error ⁽⁴⁾			140	250	μV
	Offset error drift ⁽⁴⁾	$T_A = 25^{\circ}C \text{ to } 85^{\circ}C$		2.5	18	µV/°C
	Full-scale error ⁽⁵⁾			±0.1%	±0.7%	
	Full-scale error drift			50		PPM/°C
	Effective input resistance ⁽⁶⁾		8			MΩ
OULOMB CO	OUNTER					1
	Input voltage range		-0.20		0.20	V
	Conversion time	Single conversion		250		ms
	Effective resolution	Single conversion	15			bits
		-0.1 V to 0.20 V		±0.007	±0.034	
	Integral nonlinearity	-0.20 V to -0.1 V		±0.007		%FSR
	Offset error ⁽⁷⁾	$T_A = 25^{\circ}C$ to $85^{\circ}C$		10		μV
	Offset error drift			0.4	2.45	µV/°C
	Full-scale error ^{(8) (9)}			±0.35%		
	Full-scale error drift			150		PPM/°C
	Effective input resistance ⁽¹⁰⁾	$T_A = 25^{\circ}C$ to $85^{\circ}C$	2.5			MΩ
NTERNAL TE	MPERATURE SENSOR					
V _(TEMP)	Temperature sensor voltage ⁽¹¹⁾			-2.0		mV/°C
OLTAGE RE	FERENCE	+	ŧ			
	Output voltage		1.215	1.225	1.230	V
	Output voltage drift			65		PPM/°C
IGH FREQU	ENCY OSCILLATOR					
f _(OSC)	Operating frequency			4.194		MHz
,	- (12) (13)		-3%	0.25%	3%	
f _(EIO)	Frequency error ⁽¹²⁾ (13)	$T_A = 20^{\circ}C$ to $70^{\circ}C$	-2%	0.25%	2%	
t _(SXO)	Start-up time ⁽¹⁴⁾			2.5	5	ms
OW FREQUE	ENCY OSCILLATOR					1
f _(LOSC)	Operating frequency			32.768		kHz
	- (13) (15)		-2.5%	0.25%	2.5%	
f _(LEIO)	Frequency error ⁽¹³⁾ (15)	$T_A = 20^{\circ}C$ to $70^{\circ}C$	-1.5%	0.25%	1.5%	
	Start-up time ⁽¹⁴⁾				500	μs

(4) Post-calibration performance and no I/O changes during conversion with SRN as the ground reference

(5) Uncalibrated performance. This gain error can be eliminated with external calibration.

(6) The A/D input is a switched-capacitor input. Since the input is switched, the effective input resistance is a measure of the average

resistance.(7) Post-calibration performance

- (8) Reference voltage for the coulomb counter is typically V_{ref} /3.969 at $V_{(REG25)}$ = 2.5 V, T_A = 25°C.
- (9) Uncalibrated performance. This gain error can be eliminated with external calibration.
- (10) The CC input is a switched capacitor input. Since the input is switched, the effective input resistance is a measure of the average resistance.
- (11) -53.7 LSB/°C
- (12) The frequency error is measured from 4.194 MHz.
- (13) The frequency drift is included and measured from the trimmed frequency at $V_{(REG25)} = 2.5V$, $T_A = 25^{\circ}C$.

(14) The startup time is defined as the time it takes for the oscillator output frequency to be $\pm 3\%$.

(15) The frequency error is measured from 32.768 kHz.

DATA FLASH CHARACTERISTICS (Over Recommended Operating Temperature and Supply Voltage)

Typical Values at $T_A = 25^{\circ}C$ and $V_{(REG25)} = 2.5 V$ (unless otherwise noted)



DATA FLASH CHARACTERISTICS (Over Recommended Operating Temperature and Supply Voltage) (continued)

Typical Values at $T_A = 25^{\circ}C$ and $V_{(REG25)} = 2.5 V$ (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
	Data retention		10			Years
	Flash programming write-cycles		20k			Cycles
t _(ROWPROG)	Row programming time	See ⁽¹⁾			2	ms
t _(MASSERASE)	Mass-erase time				200	ms
t _(PAGEERASE)	Page-erase time				20	ms
I(DDPROG)	Flash-write supply current			5	10	mA
I(DDERASE)	Flash-erase supply current			5	10	mA
RAM BACK	JP					
1	DD data ratastian input surrant	$V_{(RBI)} > V_{(RBI)MIN}, V_{REG25} < V_{IT-}, T_A = 85^{\circ}C$		1000	2500	2
I _(RB)	RB data-retention input current	$V_{(RBI)} > V_{(RBI)MIN}, V_{REG25} < V_{IT-}, T_A = 25^{\circ}C$		90	220	– nA
V _(RB)	RB data-retention input voltage ⁽¹⁾		1.7			V

(1) Specified by design. Not production tested.

SMBUS TIMING CHARACTERISTICS

 $T_A = -40^{\circ}$ C to 85°C Typical Values at $T_A = 25^{\circ}$ C and $V_{REG25} = 2.5$ V (Unless Otherwise Noted)

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
f _(SMB)	SMBus operating frequency	SLAVE mode, SMBC 50% duty cycle	10		100	kHz
f _(MAS)	SMBus master clock frequency	MASTER mode, No clock low slave extend		51.2		kHz
t _(BUF)	Bus free time between start and stop (see Figure 1)		4.7			μs
t _(HD:STA)	Hold time after (repeated) start (see Figure 1)		4			μs
t _(SU:STA)	Repeated start setup time (see Figure 1)		4.7			μs
t _(SU:STO)	Stop setup time (see Figure 1)		4			μs
t _(HD:DAT)	Data hold time (and Figure 1)	RECEIVE mode	0			ns
	Data hold time (see Figure 1)	TRANSMIT mode	300			
t _(SU:DAT)	Data setup time (see Figure 1)		250			ns
t _(TIMEOUT)	Error signal/detect (see Figure 1)	See ⁽¹⁾	25		35	μs
t _(LOW)	Clock low period (see Figure 1)		4.7			μs
t _(HIGH)	Clock high period (see Figure 1)	See ⁽²⁾	4		50	μs
t _(LOW:SEXT)	Cumulative clock low slave extend time	See ⁽³⁾			25	μs
t _(LOW:MEXT)	Cumulative clock low master extend time (see Figure 1)	See ⁽⁴⁾			10	μs
t _f	Clock/data fall time	See ⁽⁵⁾			300	ns
tr	Clock/data rise time	See ⁽⁶⁾			1000	ns

The bq20z95 times out when any clock low exceeds t_(TIMEOUT).
 t_(HIGH), Max, is the minimum bus idle time. SMBC = SMBD = 1 for t > 50 ms causes reset of any transaction involving bq20z95 that is in progress. This specification is valid when the NC_SMB control bit remains in the default cleared state (CLK[0]=0).

t_(LOW:SEXT) is the cumulative time a slave device is allowed to extend the clock cycles in one message from initial start to the stop. (3)

t_(LOW:MEXT) is the cumulative time a master device is allowed to extend the clock cycles in one message from initial start to the stop. (4)

(5) Rise time $t_r = VILMAX - 0.15$) to (VIHMIN + 0.15)

Fall time $t_f = 0.9V_{DD}$ to (VILMAX – 0.15) (6)



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A. SCLKACK is the acknowledge-related clock pulse generated by the master.

Figure 1. SMBus Timing Diagram



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FEATURE SET

Primary (1st Level) Safety Features

The bq20z95 supports a wide range of battery and system protection features that can easily be configured. The primary safety features include:

- Cell over/undervoltage protection
- Charge and discharge overcurrent
- Short circuit
- Charge and discharge overtemperature
- AFE watchdog

Secondary (2nd Level) Safety Features

The secondary safety features of the bq20z95 can be used to indicate more serious faults via the SAFE (pin 7). This pin can be used to blow an in-line fuse to permanently disable the battery pack from charging or discharging. The secondary safety protection features include:

- Safety overvoltage
- Safety overcurrent in Charge and Discharge
- Safety overtemperature in Charge and Discharge
- Charge FET and 0-V Charge FET fault
- Discharge FET fault
- AFE communication fault

Charge Control Features

The bq20z95 charge control features include:

- Reports the appropriate charging current needed for constant current charging and the appropriate charging voltage needed for constant voltage charging to a smart charger using SMBus broadcasts.
- Determines the chemical state of charge of each battery cell using Impedance Track and can reduce the charge difference of the battery cells in fully charged state of the battery pack gradually using cell balancing algorithm during charging. This prevents fully charged cells from overcharging and causing excessive degradation and also increases the usable pack energy by preventing premature charge termination
- Supports pre-charging/zero-volt charging
- Support fast charging
- Supports charge inhibit and charge suspend if battery pack temperature is out of temperature range
- Reports charging fault and also indicate charge status via charge and discharge alarms.

Gas Gauging

The bq20z95 uses the Impedance Track technology to measure and calculate the available charge in battery cells. The achievable accuracy is better than 1% error over the lifetime of the battery and there is no full charge discharge learning cycle required.

See *Theory and Implementation of Impedance Track Battery Fuel-Gauging Algorithm* application note (SLUA364) for further details.

Authentication

The bq20z95 supports authentication by the host using SHA-1.

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Power Modes

The bq20z95 supports three power modes to reduce power consumption:

- In NORMAL mode, the bq20z95 performs measurements, calculations, protection decisions and data updates in 1-s intervals. Between these intervals, the bq20z95 is in a reduced power stage.
- In SLEEP mode, the bq20z95 performs measurements, calculations, protection decisions, and data updates in adjustable time intervals. Between these intervals, the bq20z95 is in a reduced power stage. The bq20z95 has a wake function that enables exit from SLEEP mode when current flow or failure is detected.
- In SHUTDOWN mode the bq20z95 is completely disabled.

CONFIGURATION

Oscillator Function

The bq20z95 fully integrates the system oscillators. Therefore, the bq20z95 requires no external components for this feature.

System Present Operation

The bq20z95 checks the PRES pin periodically (1s). If PRES input is pulled to ground by external system, the bq20z95 detects this as system present.

BATTERY PARAMETER MEASUREMENTS

The bq20z95 uses an integrating delta-sigma analog-to-digital converter (ADC) for current measurement, and a second delta-sigma ADC for individual cell and battery voltage and temperature measurement.

Charge and Discharge Counting

The integrating delta-sigma ADC measures the charge/discharge flow of the battery by measuring the voltage drop across a small-value sense resistor between the SR1 and SR2 pins. The integrating ADC measures bipolar signals from –0.25 V to 0.25 V. The bq20z95 detects charge activity when $V_{SR} = V_{(SRP)} - V_{(SRN)}$ is positive and discharge activity when $V_{SR} = V_{(SRP)} - V_{(SRN)}$ is negative. The bq20z95 continuously integrates the signal over time, using an internal counter. The fundamental rate of the counter is 0.65 nVh.

Voltage

The bq20z95 updates the individual series cell voltages at 1-s intervals. The internal ADC of the bq20z95 measures the voltage, and scales and calibrates it appropriately. This data is also used to calculate the impedance of the cell for the Impedance Track gas-gauging.

Current

The bq20z95 uses the SRP and SRN inputs to measure and calculate the battery charge and discharge current using a 5-m Ω to 20-m Ω typ. sense resistor.

Auto Calibration

The bq20z95 provides an auto-calibration feature to cancel the voltage offset error across SRN and SRP for maximum charge measurement accuracy. The bq20z95 performs auto-calibration when the SMBus lines stay low continuously for a minimum of 5 s.

Temperature

The bq20z95 has an internal temperature sensor and two external temperature sensor inputs TS1 and TS2 used in conjunction with two identical NTC thermistors (default are Semitec 103AT) to sense the battery environmental temperature. The bq20z95 can be configured to use internal or up to two external temperature sensors.



COMMUNICATIONS

The bq20z95 uses SMBus v1.1 with MASTER mode and package error checking (PEC) options per the SBS specification.

SMBus On and Off State

The bq20z95 detects an SMBus off state when SMBC and SMBD are logic-low for \geq 2 seconds. Clearing this state requires either SMBC or SMBD to transition high. Within 1 ms, the communication bus is available.

SBS Commands

SBS Cmd	Mode	Name	Format	Size in Bytes	Min Value	Max Value	Default Value	Unit
0x00	R/W	ManufacturerAccess	hex	2	0x0000	Oxffff	_	
0x01	R/W	RemainingCapacityAlarm	unsigned int	2	0	65535	_	mAh or 10 mWh
0x02	R/W	RemainingTimeAlarm	unsigned int	2	0	65535	_	min
0x03	R/W	BatteryMode	hex	2	0x0000	0xffff	—	
0x04	R/W	AtRate	signed int	2	-32768	32767	—	mA or 10 mW
0x05	R	AtRateTimeToFull	unsigned int	2	0	65535		min
0x06	R	AtRateTimeToEmpty	unsigned int	2	0	65535	—	min
0x07	R	AtRateOK	unsigned int	2	0	65535	_	
0x08	R	Temperature	unsigned int	2	0	65535	_	0.1°K
0x09	R	Voltage	unsigned int	2	0	20000	_	mV
0x0a	R	Current	signed int	2	-32768	32767	—	mA
0x0b	R	AverageCurrent	signed int	2	-32768	32767	—	mA
0x0c	R	MaxError	unsigned int	1	0	100	—	%
0x0d	R	RelativeStateOfCharge	unsigned int	1	0	100	—	%
0x0e	R	AbsoluteStateOfCharge	unsigned int	1	0	100	_	%
0x0f	R/W	RemainingCapacity	unsigned int	2	0	65535	_	mAh or 10 mWh
0x10	R	FullChargeCapacity	unsigned int	2	0	65535	_	mAh or 10 mWh
0x11	R	RunTimeToEmpty	unsigned int	2	0	65535	—	min
0x12	R	AverageTimeToEmpty	unsigned int	2	0	65535	—	min
0x13	R	AverageTimeToFull	unsigned int	2	0	65535	—	min
0x14	R	ChargingCurrent	unsigned int	2	0	65535	_	mA
0x15	R	ChargingVoltage	unsigned int	2	0	65535	_	mV
0x16	R	BatteryStatus	unsigned int	2	0x0000	Oxffff	—	
0x17	R/W	CycleCount	unsigned int	2	0	65535	_	
0x18	R/W	DesignCapacity	unsigned int	2	0	65535	_	mAh or 10 mWh
0x19	R/W	DesignVoltage	unsigned int	2	7000	16000	14400	mV
0x1a	R/W	SpecificationInfo	unsigned int	2	0x0000	0xffff	0x0031	
0x1b	R/W	ManufactureDate	unsigned int	2	0	65535	0	
0x1c	R/W	SerialNumber	hex	2	0x0000	Oxffff	0x0001	
0x20	R/W	ManufacturerName	String	11+1	_	_	Texas Instruments	ASCII
0x21	R/W	DeviceName	String	7+1	_	_	bq20z95	ASCII
0x22	R/W	DeviceChemistry	String	4+1	_		LION	ASCII
0x23	R	ManufacturerData	String	14+1	_	_	_	ASCII

Table 2. SBS COMMANDS

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NSTRUMENTS

Texas

SBS Cmd	Mode	Name	Format	Size in Bytes	Min Value	Max Value	Default Value	Unit
0x2f	R/W	Authenticate	String	20+1	_	—		ASCII
0x3c	R	CellVoltage4	unsigned int	2	0	65535	_	mV
0x3d	R	CellVoltage3	unsigned int	2	0	65535	_	mV
0x3e	R	CellVoltage2	unsigned int	2	0	65535	_	mV
0x3f	R	CellVoltage1	unsigned int	2	0	65535	-	mV

Table 3. EXTENDED SBS COMMANDS

SBS Cmd	Mode	Name	Format	Size in Bytes	Min Value	Max Value	Default Value	Unit
0x45	R	AFEData	String	11+1	—	—	_	ASCII
0x46	R/W	FETControl	hex	1	0x00	Oxff	_	
0x4f	R	StateOfHealth	unsigned int	1	0	100	_	%
0x51	R	SafetyStatus	hex	2	0x0000	Oxffff	_	
0x53	R	PFStatus	hex	2	0x0000	Oxffff	_	
0x54	R	OperationStatus	hex	2	0x0000	Oxffff	_	
0x55	R	ChargingStatus	hex	2	0x0000	Oxffff	_	
0x57	R	ResetData	hex	2	0x0000	Oxffff	_	
0x5a	R	PackVoltage	unsigned int	2	0	65535	_	mV
0x5d	R	AverageVoltage	unsigned int	2	0	65535	_	mV
0x60	R/W	UnSealKey	hex	4	0x00000000	Oxffffffff	_	
0x61	R/W	FullAccessKey	hex	4	0x00000000	Oxffffffff	_	
0x62	R/W	PFKey	hex	4	0x00000000	Oxffffffff	_	
0x63	R/W	AuthenKey3	hex	4	0x00000000	Oxffffffff	_	
0x64	R/W	AuthenKey2	hex	4	0x00000000	Oxffffffff	_	
0x65	R/W	AuthenKey1	hex	4	0x00000000	Oxffffffff	_	
0x66	R/W	AuthenKey0	hex	4	0x00000000	Oxffffffff	_	
0x70	R/W	ManufacturerInfo	String	31+1	—	—	_	
0x71	R/W	SenseResistor	unsigned int	2	0	65535	_	μΩ
0x77	R/W	DataFlashSubClassID	hex	2	0x0000	Oxffff	_	
0x78	R/W	DataFlashSubClassPage1	hex	32		_	_	
0x79	R/W	DataFlashSubClassPage2	hex	32	—	—	_	
0x7a	R/W	DataFlashSubClassPage3	hex	32	—	_	_	
0x7b	R/W	DataFlashSubClassPage4	hex	32			_	
0x7c	R/W	DataFlashSubClassPage5	hex	32			_	
0x7d	R/W	DataFlashSubClassPage6	hex	32	—	_	_	
0x7e	R/W	DataFlashSubClassPage7	hex	32	—	—	_	
0x7f	R/W	DataFlashSubClassPage8	hex	32	_	_	_	



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Application Schematic





7-Nov-2014

PACKAGING INFORMATION

Orderable Device		Package Type	•	Pins	•	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking	Samples
	(1)		Drawing		Qty	(2)	(6)	(3)		(4/5)	
BQ20Z95DBT	NRND	TSSOP	DBT	44	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 85	20Z95DBT	
BQ20Z95DBTG4	NRND	TSSOP	DBT	44	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 85	20Z95DBT	
BQ20Z95DBTR	NRND	TSSOP	DBT	44	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 85	20Z95DBT	
BQ20Z95DBTRG4	NRND	TSSOP	DBT	44		TBD	Call TI	Call TI	-40 to 85		

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

⁽²⁾ Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes. **Pb-Free (RoHS Exempt):** This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

⁽³⁾ MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

⁽⁴⁾ There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(⁵⁾ Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

⁽⁶⁾ Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.



7-Nov-2014

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PACKAGE MATERIALS INFORMATION

www.ti.com

TAPE AND REEL INFORMATION

REEL DIMENSIONS

Texas Instruments





TAPE DIMENSIONS



A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

TAPE AND REEL INFORMATION

*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
BQ20Z95DBTR	TSSOP	DBT	44	2000	330.0	24.4	6.8	11.7	1.6	12.0	24.0	Q1

TEXAS INSTRUMENTS

www.ti.com

PACKAGE MATERIALS INFORMATION

14-Jul-2012



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
BQ20Z95DBTR	TSSOP	DBT	44	2000	367.0	367.0	45.0

DBT (R-PDSO-G44)

PLASTIC SMALL OUTLINE



A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.
B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion.



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